

30 V, single N-channel Trench MOSFET 29 October 2013

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Very fast switching
- Trench MOSFET technology
- ESD protection
- Low threshold voltage

3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	30	V
V _{GS}	gate-source voltage	_		-20	-	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	-	200	mA
Static characteristics							
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I _D = 100 mA; pulsed; t _p ≤ 300 µs; δ ≤ 0.02 ; T _j = 25 °C		-	2.7	4.5	Ω

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain	1 ☐ ☐ 2 TO-236AB (SOT23)	G S 017aaa255

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
NX3020NAK	TO-236AB	plastic surface-mounted package; 3 leads	SOT23			

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
NX3020NAK	%CU

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

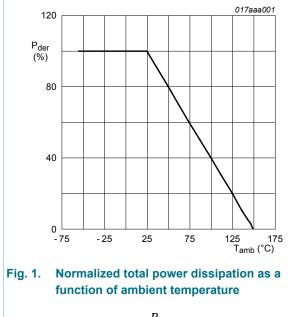
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	30	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	200	mA
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	125	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	800	mA
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	300	mW
			[1]	-	360	mW

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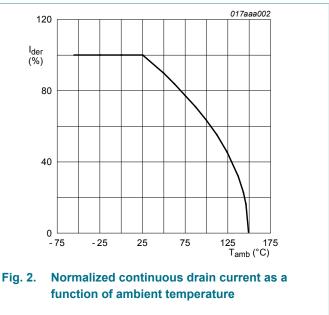
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Symbol	Parameter	Conditions		Min	Max	Unit	
		T _{sp} = 25 °C		-	1060	mW	
Tj	junction temperature			-55	150	°C	
T _{amb}	ambient temperature			-55	150	°C	
T _{stg}	storage temperature			-65	150	°C	
Source-drain diode							
I _S	source current	T _{amb} = 25 °C	[1]	-	200	mA	

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².
Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



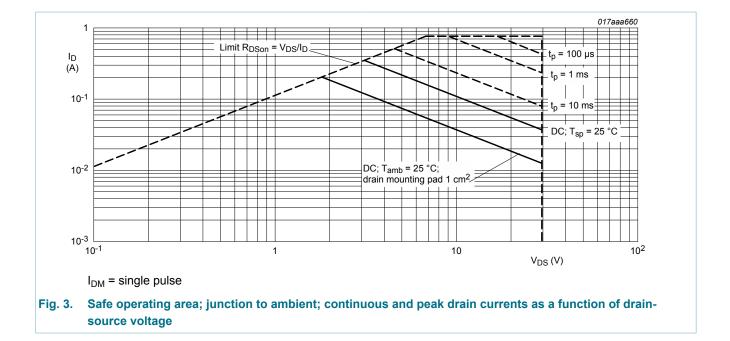
$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$



$$I_{der} = \frac{I_D}{I_{D(25^\circ C)}} \times 100 \%$$

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9. Thermal characteristics

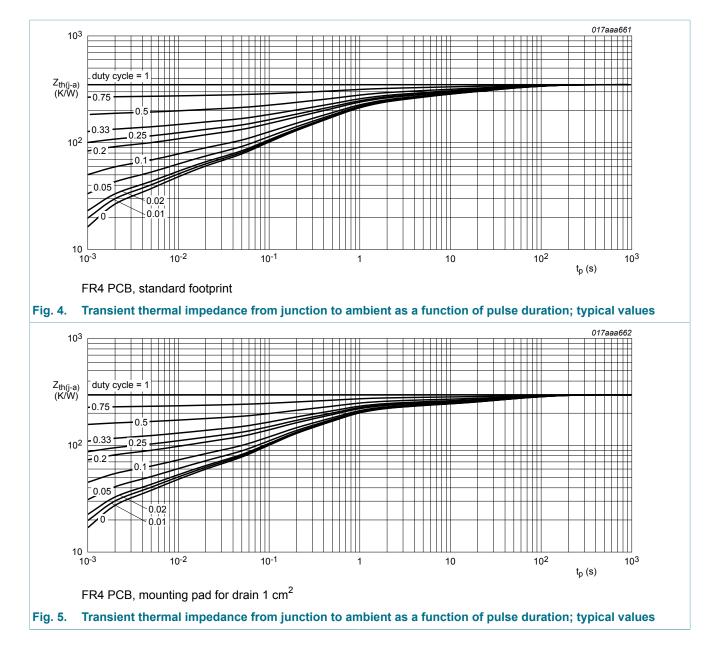
Table 6. Thermal characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
R _{th(j-a)}	thermal resistance from junction to ambient	-	[1]	-	350	400	K/W	
			[2]	-	300	340	K/W	
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	115	K/W	

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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10. Characteristics

Table 7. Cl	haracteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Static characteristics								
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C		30	-	-	V	
V _{GSth}	gate-source threshold voltage	I_D = 250 A; V_{DS} = V_{GS} ; T_j = 25 °C		0.8	1.2	1.5	V	
I _{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C		-	-	1	μA	
		V _{DS} = 30 V; V _{GS} = 0 V; T _j = 150 °C		-	-	10	μA	
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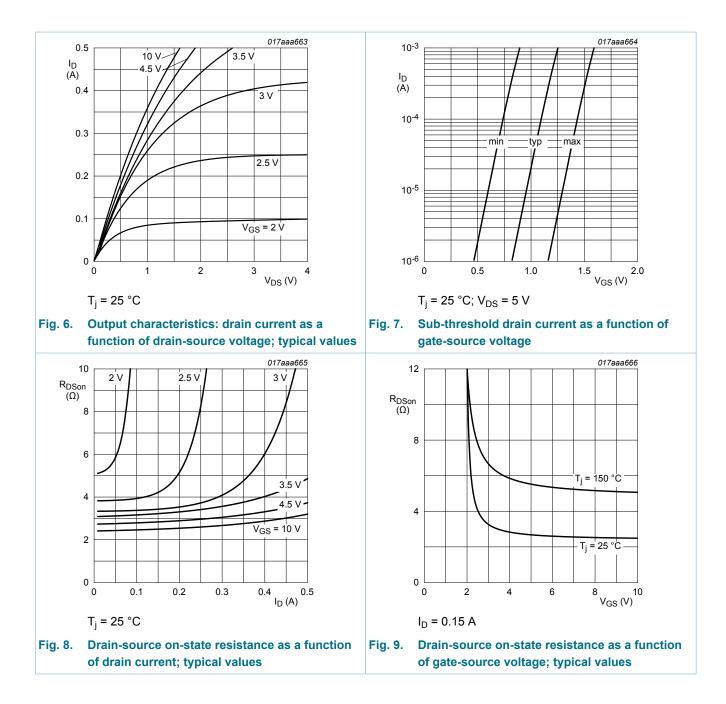
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	3.5	μA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-3.5	μA
		V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μA
		V_{GS} = -10 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-1	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	0.5	μA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-0.5	μA
R _{DSon}	drain-source on-state resistance	$\label{eq:VGS} \begin{array}{l} V_{GS} = 10 \; V; \; I_{D} = 100 \; mA; \; pulsed; \\ t_{p} \leq 300 \; \mu s; \; \delta \leq 0.02 \; ; \; T_{j} = 25 \; ^{\circ} C \end{array}$	-	2.7	4.5	Ω
		V_{GS} = 10 V; I _D = 100 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02 ; T _j = 150 °C	-	5.5	9.2	Ω
		V_{GS} = 4.5 V; I _D = 100 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02 ; T _j = 25 °C	-	3	5.2	Ω
		V_{GS} = 2.5 V; I _D = 10 mA; pulsed; t _p ≤ 300 µs; δ ≤ 0.02 ; T _j = 25 °C	-	4	13	Ω
9fs	forward transconductance	V_{DS} = 10 V; I _D = 150 mA; pulsed; t _p ≤ 300 µs; δ ≤ 0.02 ; T _j = 25 °C	320	-	-	mS
Dynamic cl	haracteristics		I			
Q _{G(tot)}	total gate charge	V_{DS} = 15 V; I _D = 150 mA; V _{GS} = 4.5 V;	-	0.34	0.44	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.11	-	nC
Q _{GD}	gate-drain charge		-	0.06	-	nC
C _{iss}	input capacitance	V_{DS} = 10 V; f = 1 MHz; V_{GS} = 0 V;	-	13	20	pF
C _{oss}	output capacitance	T _j = 25 °C	-	2.6	-	pF
C _{rss}	reverse transfer capacitance		-	1.1	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 20 V; R _L = 250 Ω; V _{GS} = 10 V;	-	5	10	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	5	-	ns
t _{d(off)}	turn-off delay time		-	34	68	ns
t _f	fall time		-	17	-	ns
Source-dra	in diode					
V _{SD}	source-drain voltage	I _S = 115 mA; V _{GS} = 0 V; T _i = 25 °C	0.47	0.7	1.2	V

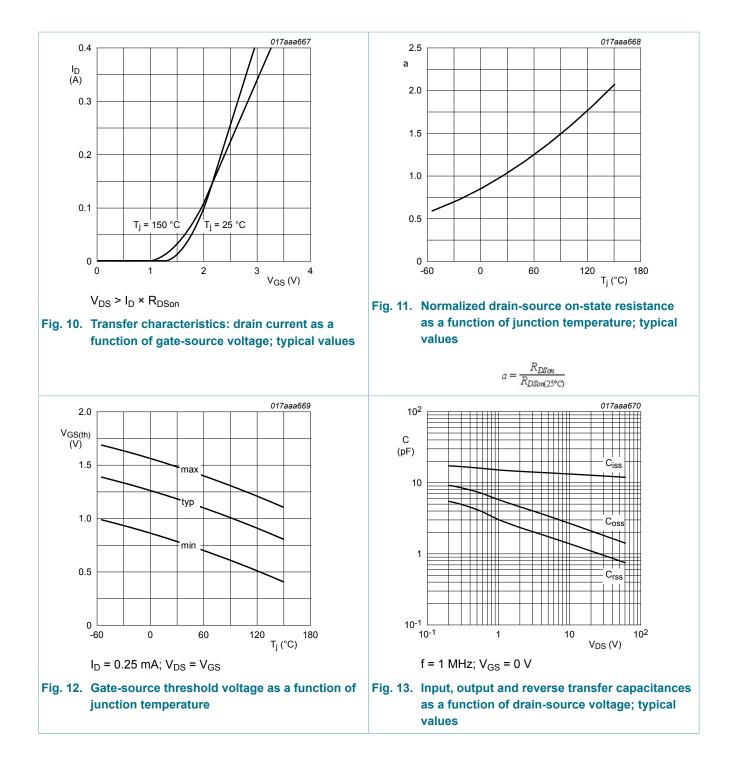
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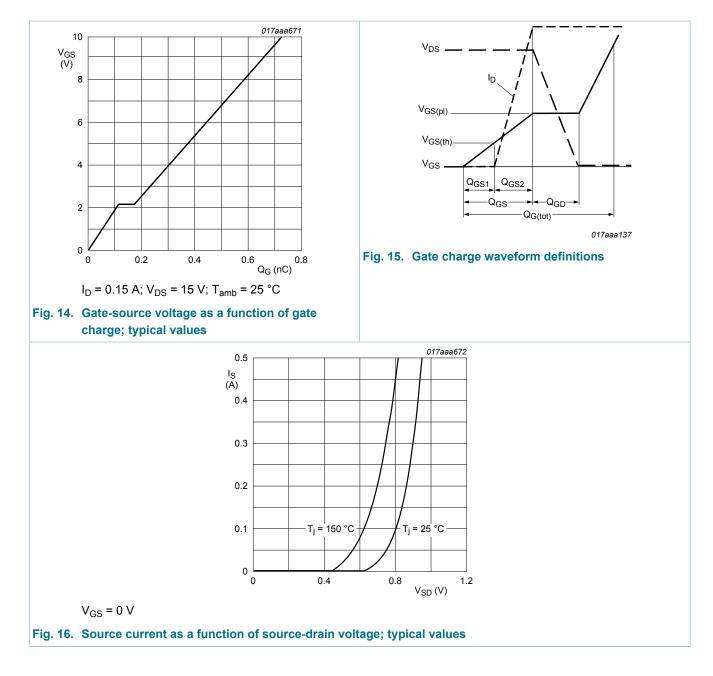
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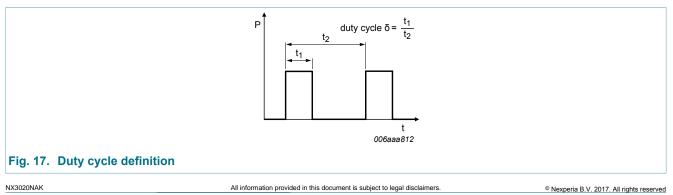
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11. Test information



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12. Package outline

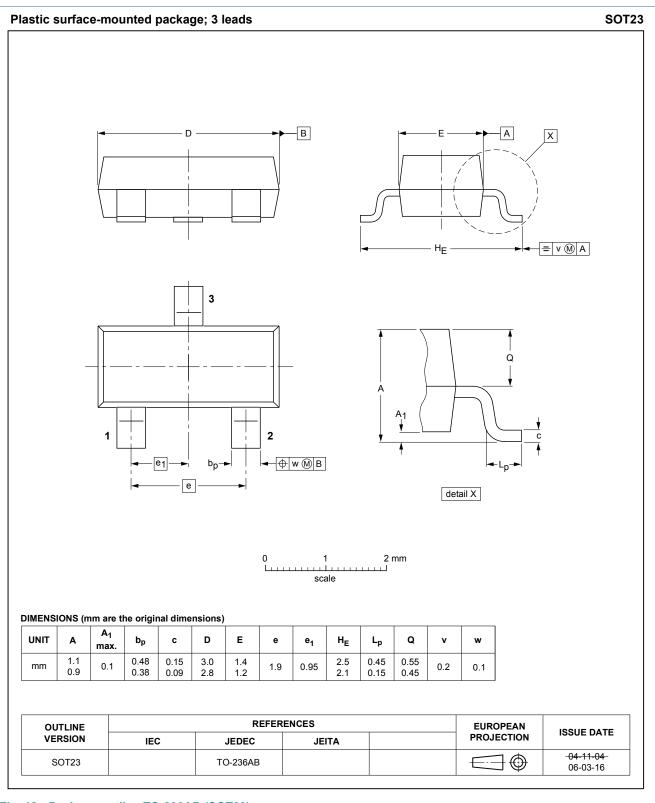


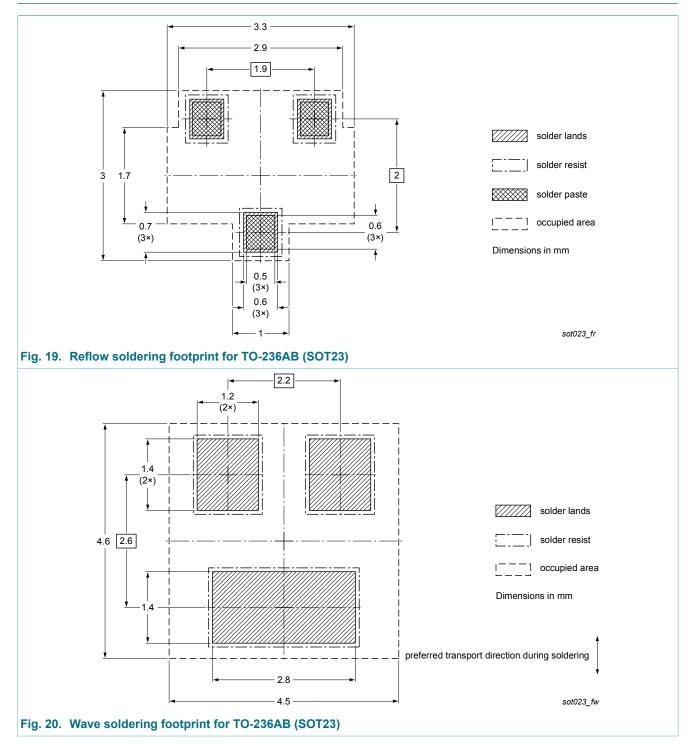
Fig. 18. Package outline TO-236AB (SOT23)

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13. Soldering



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14. Revision history

Table 8. Revision his	story						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
NX3020NAK v.2	20131029	Product data sheet	-	NX3020NAK v.1			
Modifications:							
NX3020NAK v.1	20121002	Product data sheet	-	-			

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15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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